

1. Description

This P-Channel 2.5V has been optimized for power management applications with a wide range of gate drive voltage (2.5V – 12V)

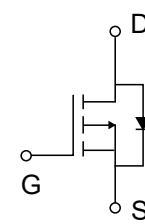
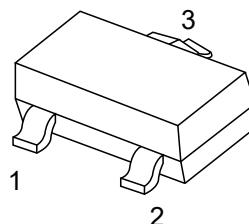
2. Features

- $V_{DS(V)} = -20V$
- $I_D = -2.4A$
- $R_{DS(ON)} = 55m\Omega (V_{GS} = -4.5V)$
- $R_{DS(ON)} = 80m\Omega (V_{GS} = -2.5V)$

3. Pinning information

| Pin | Symbol | Description |
|-----|--------|-------------|
| 1 | G | GATE |
| 2 | S | SOURCE |
| 3 | D | DRAIN |

SOT-23



4. Maximum ratings ($T_A = 25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Value | Units |
|---|-----------------|------------|-------|
| Drain-Source Voltage | V_{DSS} | -20 | V |
| Gate-Source Voltage | V_{GSS} | ± 12 | V |
| Drain Current – Continuous (Note 1a) – Pulsed | I_D | -2.4 | A |
| | | -10 | |
| Maximum Power Dissipation (Note 1a) (Note 1b) | P_D | 0.5 | W |
| | | 0.46 | |
| Storage Junction Temperature Range | T_J, T_{STG} | -55 to 150 | °C |
| Thermal Characteristics | | | |
| Thermal Resistance, Junction-to-Ambient (Note 1a) | $R_{\theta JA}$ | 250 | °C/W |
| Thermal Resistance, Junction-to-Case (Note 1) | $R_{\theta JC}$ | 75 | °C/W |



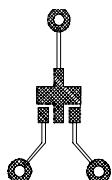
5. Static Electrical Characteristics ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
|---|--|---|------|------|------|----------------------------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $I_D = -250\mu\text{A}, V_{GS} = 0\text{V}$ | -20 | | | V |
| Breakdown Voltage Temperature Coefficient | $\frac{\Delta \text{BV}_{\text{DSS}}}{\Delta T_J}$ | $I_D = -250\mu\text{A}$ Referenced to 25°C | | -12 | | $\text{mV}/^\circ\text{C}$ |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = -16\text{V}, V_{GS} = 0\text{V}$ | | -1 | | μA |
| Gate-Body Leakage, Forward | I_{GSSF} | $V_{DS} = 0\text{V}, V_{GS} = -16\text{V}$ | | 100 | | nA |
| Gate-Body Leakage, Reverse | I_{GSSR} | $V_{DS} = 0\text{V}, V_{GS} = -12\text{V}$ | | -100 | | nA |
| On Characteristics (Note 2) | | | | | | |
| Gate Threshold Voltage | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}, I_D = -250\mu\text{A}$ | -0.6 | -1 | -1.5 | V |
| Gate Threshold Voltage Temperature Coefficient | $\frac{\Delta V_{GS(\text{th})}}{\Delta T_J}$ | $I_D = -250\mu\text{A}$ Referenced to 25°C | | 3 | | $\text{mV}/^\circ\text{C}$ |
| Static Drain-Source On-Resistance | $R_{DS(\text{ON})}$ | $V_{GS} = -4.5\text{V}, I_D = -2.4\text{A}$ $V_{GS} = -2.5\text{V}, I_D = -2\text{A}$ | 44 | 55 | | $\text{m}\Omega$ |
| On-State Drain Current | $I_{D(\text{ON})}$ | $V_{GS} = -4.5\text{V}, V_{DS} = -5\text{V}$ | -10 | | | A |
| Forward Transconductance | g_{FS} | $V_{DS} = -5\text{V}, I_D = -2.4\text{A}$ | | 10 | | S |
| Dynamic Characteristics | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS} = -10\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$ | | 882 | | pF |
| Output Capacitance | C_{oss} | | | 211 | | pF |
| Reverse Transfer Capacitance | C_{rss} | | | 112 | | pF |
| SWITCHING PARAMETERS (Note 2) | | | | | | |
| Turn-On Delay Time | $t_{D(\text{on})}$ | $V_{DD} = -10\text{V}, I_D = -1\text{A}$ $V_{GS} = -4.5\text{V}, R_{\text{GEN}} = 3\Omega$ | | 13 | 23 | ns |
| Turn-On Rise Time | t_r | | | 11 | 20 | ns |
| Turn-Off Delay Time | $t_{D(\text{off})}$ | | | 25 | 40 | ns |
| Turn-Off Fall Time | t_f | | | 15 | 27 | ns |
| Total Gate Charge | Q_g | $V_{DS} = -10\text{V}, I_D = -2.4\text{A}$ $V_{GS} = -4.5\text{V}$ | | 9 | 14 | nC |
| Gate-Source Charge | Q_{gs} | | | 2 | | nC |
| Gate-Drain Charge | Q_{gd} | | | 3 | | nC |

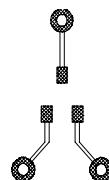


| Drain–Source Diode Characteristics and Maximum Ratings | | | | | | |
|--|----------|----------------------------------|--|------|-------|---|
| Maximum Continuous Drain–Source Diode Forward Current | I_S | | | | -0.42 | A |
| | | | | | | |
| Drain–Source Diode Forward Voltage | V_{SD} | $V_{GS}=0V, I_S=-0.42A$ (Note 2) | | -0.7 | -1.2 | V |

1. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a) 250°C/W when mounted on a
0.02 in² pad of 2 oz. copper.



b) 270°C/W when mounted on a
minimum pad.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width $\leq 300 \mu s$, Duty Cycle $\leq 2.0\%$



6.1 Typical Characteristics

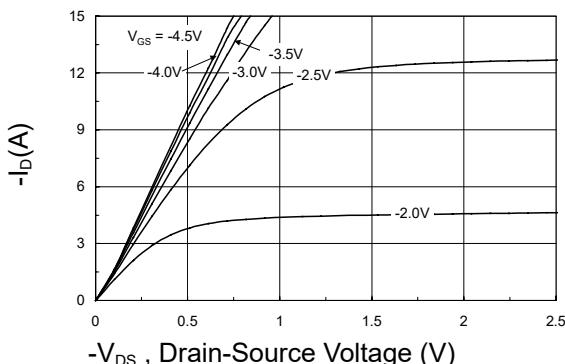


Figure 1: On-Region Characteristics.

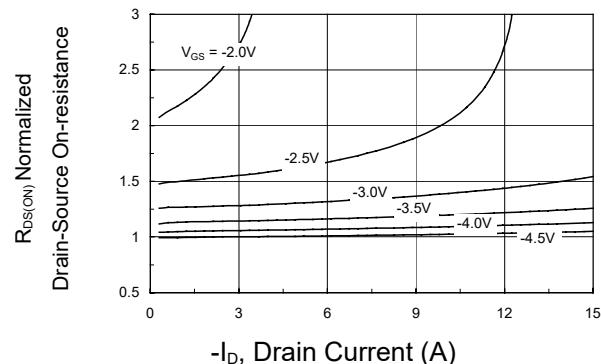


Figure 2: On-Resistance Variation with Drain Current and Gate Voltage.

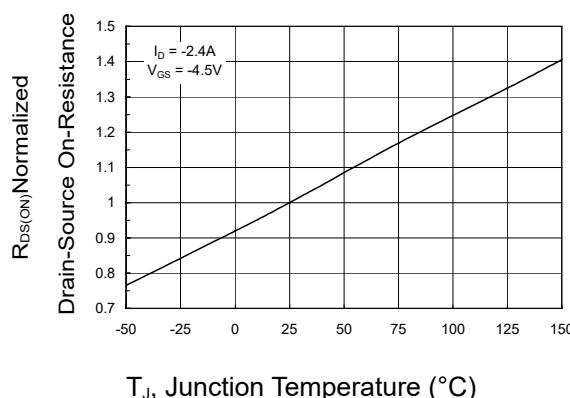


Figure 3: On-Resistance Variation with Temperature.

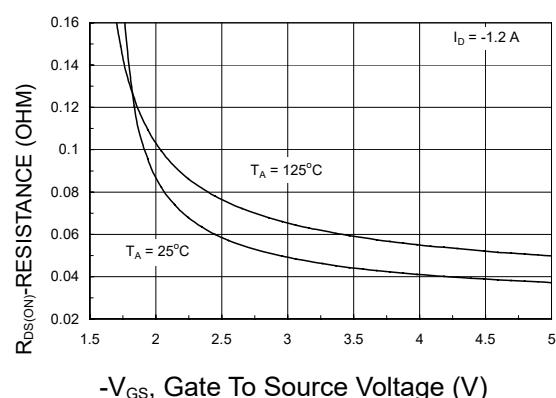


Figure 4: On-Resistance Variation with Gate-to-Source Voltage.

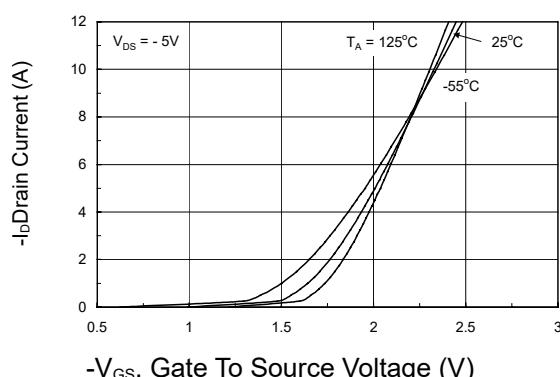


Figure 5: Transfer Characteristics.

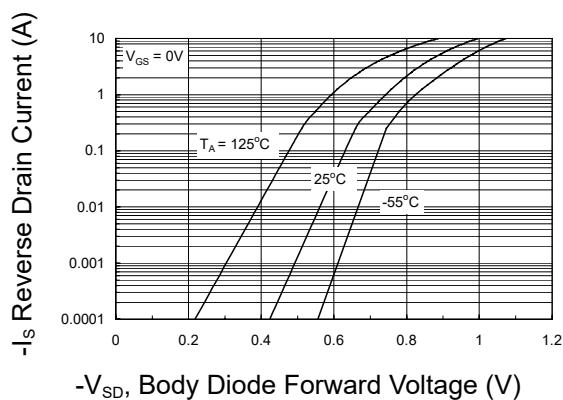
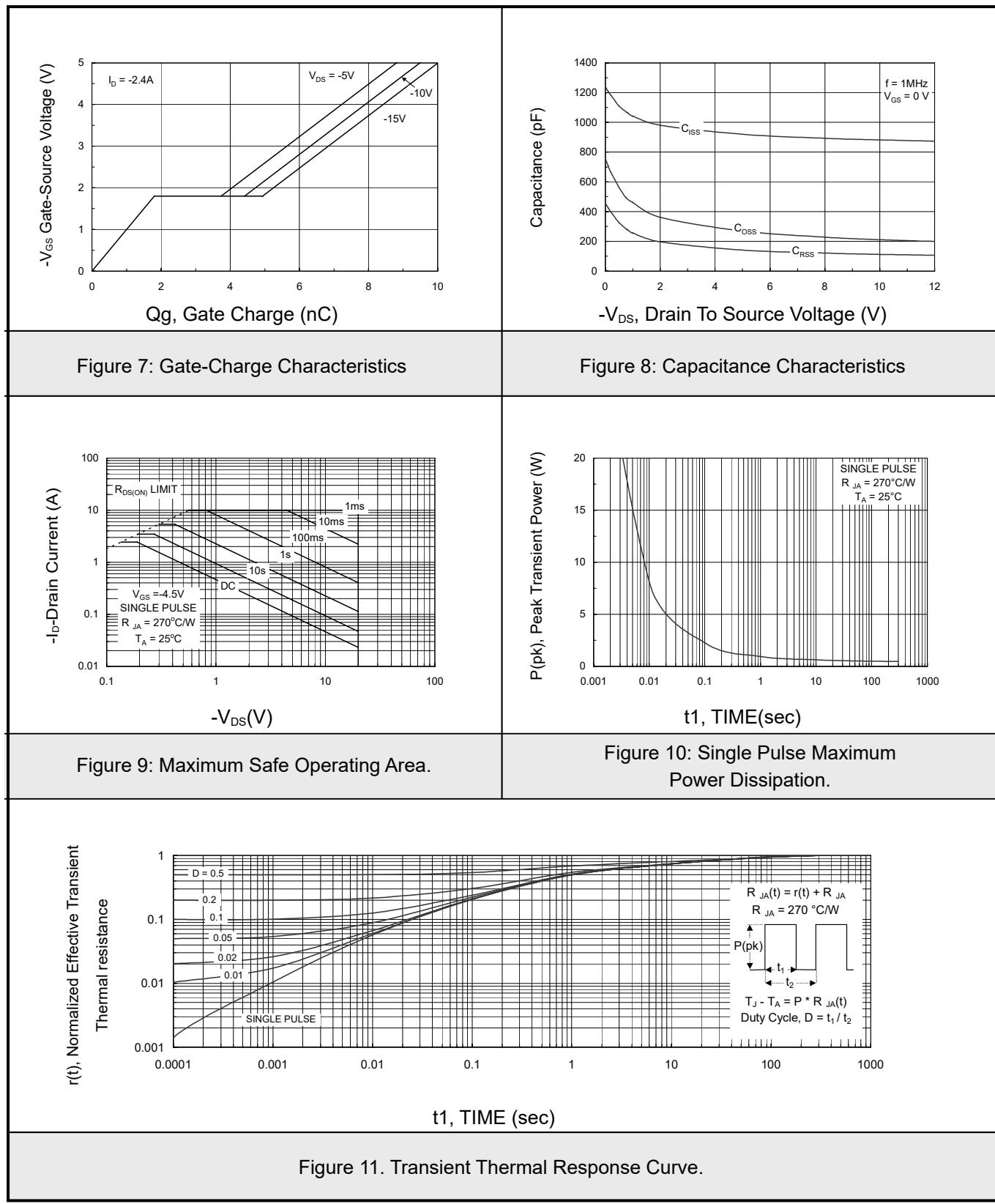


Figure 6: . Body Diode Forward Voltage Variation with Source Current and Temperature.

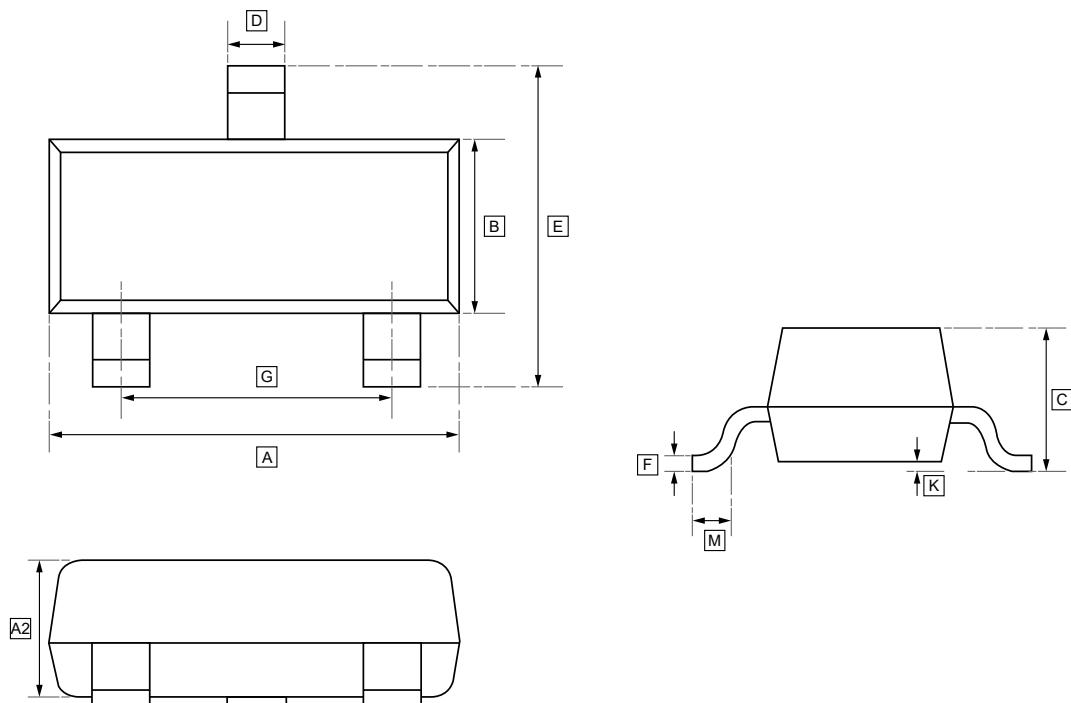


6.2 Typical Characteristics





7.SOT-23 Package Outline Dimensions

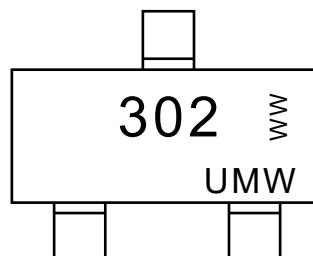


DIMENSIONS (mm are the original dimensions)

| Symbol | A | B | C | D | E | G | K | M | A2 | F |
|------------|------|------|------|------|------|------|------|------|------|-------|
| Min | 2.85 | 1.20 | 0.90 | 0.40 | 2.25 | 1.80 | 0.00 | 0.30 | 0.95 | 0.095 |
| Max | 3.04 | 1.40 | 1.10 | 0.50 | 2.55 | 2.00 | 0.10 | - | 1.05 | 0.115 |



8.Ordering information



WW: Batch Code

| Order Code | Package | Base QTY | Delivery Mode |
|-------------|---------|----------|---------------|
| UMW FDN302P | SOT-23 | 3000 | Tape and reel |



9.Disclaimer

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